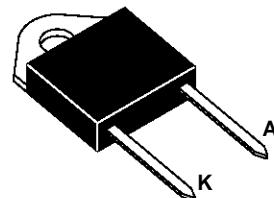


## FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING
- INSULATED: Capacitance 15pF

Insulating voltage 2500 VRSM



Isolated  
DOP3I  
(Plastic)

### SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

### ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		1000	V
$V_{RSM}$	Non Repetitive Peak Reverse Voltage		1000	V
$I_{FRM}$	Repetitive Peak Forward Current	$t_p \leq 10\mu s$	375	A
$I_F$ (RMS)	RMS Forward Current		70	A
$I_F$ (AV)	Average Forward Current	$T_c = 50^\circ C$ $\delta = 0.5$	30	A
$I_{FSM}$	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	200	A
P	Power Dissipation	$T_c = 50^\circ C$	60	W
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 40 to +150	$^\circ C$

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th}$ (j - c)	Junction-case	1.6	$^\circ C/W$

## ELECTRICAL CHARACTERISTICS

### STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$I_R$	$T_j = 25^\circ C$	$V_R = V_{RRM}$			100	$\mu A$
	$T_j = 100^\circ C$				5	mA
$V_F$	$T_j = 25^\circ C$	$I_F = 30A$			1.9	V
	$T_j = 100^\circ C$				1.8	

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$t_{rr}$	$T_j = 25^\circ C$	$I_F = 1A$	$di_F/dt = -15A/\mu s$	$V_R = 30V$		165	ns
		$I_F = 0.5A$	$I_R = 1A$	$I_{rr} = 0.25A$		70	

### TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$t_{IRM}$	$di_F/dt = -120A/\mu s$	$V_{CC} = 200 V$	$I_F = 30A$			200	ns
	$di_F/dt = -240A/\mu s$					120	
$I_{RM}$	$di_F/dt = -120A/\mu s$	$L_p \leq 0.05\mu H$	$T_j = 100^\circ C$			19.5	A
	$di_F/dt = -240A/\mu s$					22	

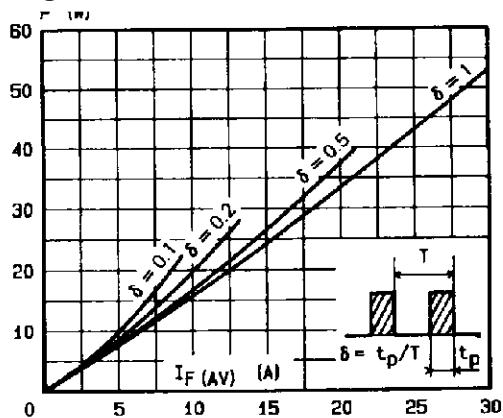
### TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^\circ C$	$V_{CC} = 200V$	$I_F = I_F(AV)$			4.5	

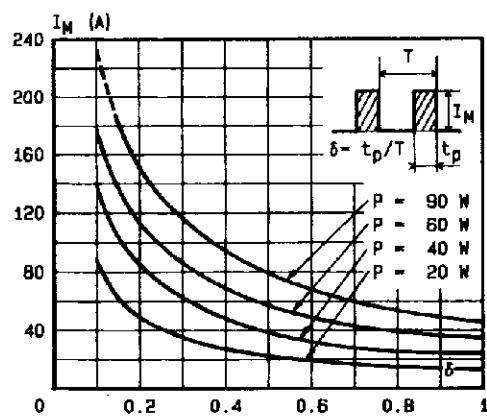
To evaluate the conduction losses use the following equations:

$$V_F = 1.47 + 0.010 I_F \quad P = 1.47 \times I_F(AV) + 0.010 I_F^2(RMS)$$

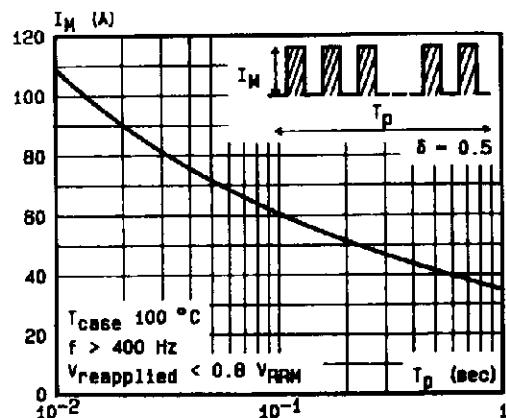
**Figure 1. Low frequency power losses versus average current**



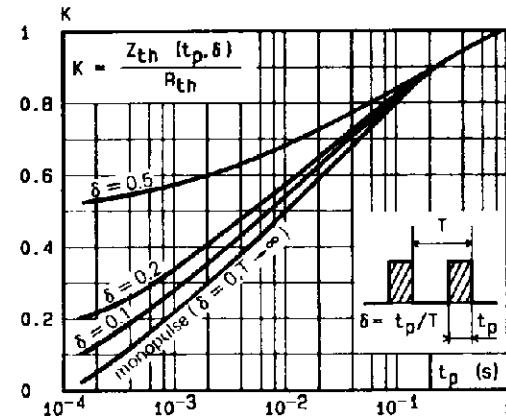
**Figure 2. Peak current versus form factor**



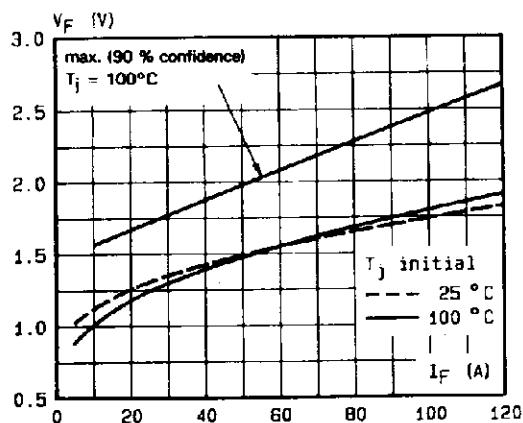
**Figure 3. Non repetitive peak surge current versus overload duration**



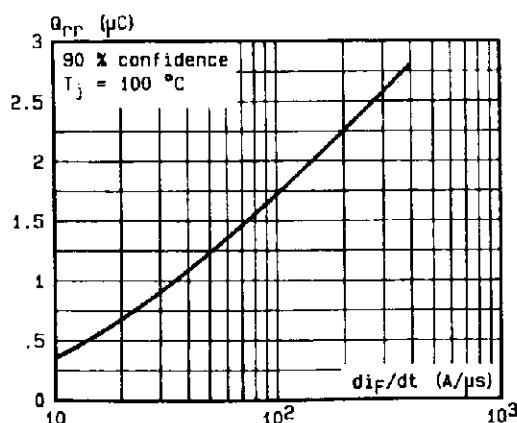
**Figure 4. Thermal impedance versus pulse width**



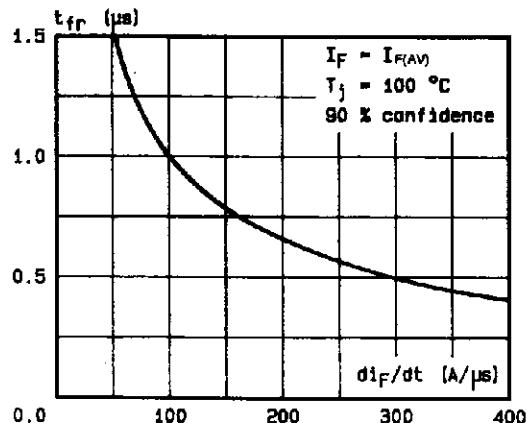
**Figure 5. Voltage drop versus forward current**



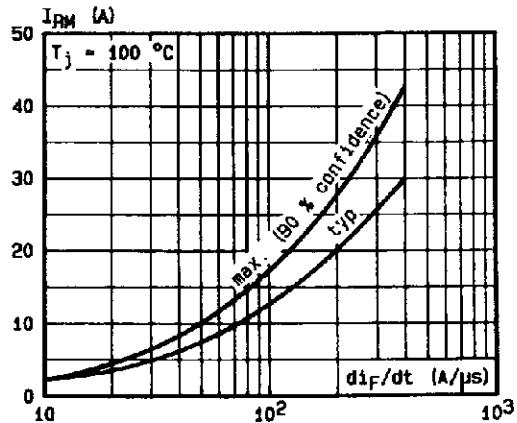
**Figure 6. Recovery charge versus  $di_F/dt$**



**Figure 7. Recovery time versus  $di_F/dt$**



**Figure 8. Peak reverse current versus  $di_F/dt$**



## BYT 30PI-1000

Figure 9. Peak forward voltage versus  $dI_F/dt$ .

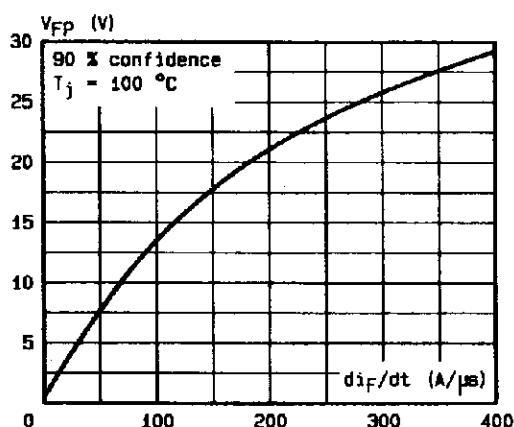


Figure 10. Dynamic parameters versus junction temperature.

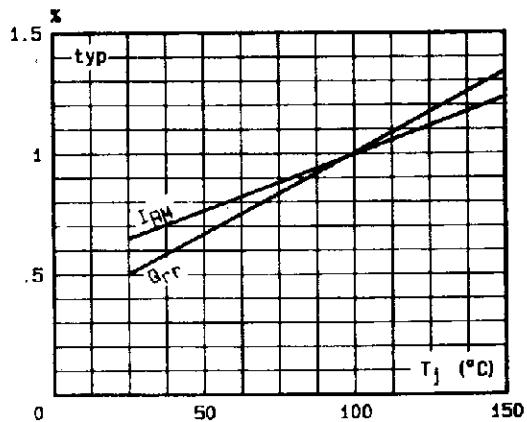


Figure 11. Turn-off switching characteristics (without series inductance).

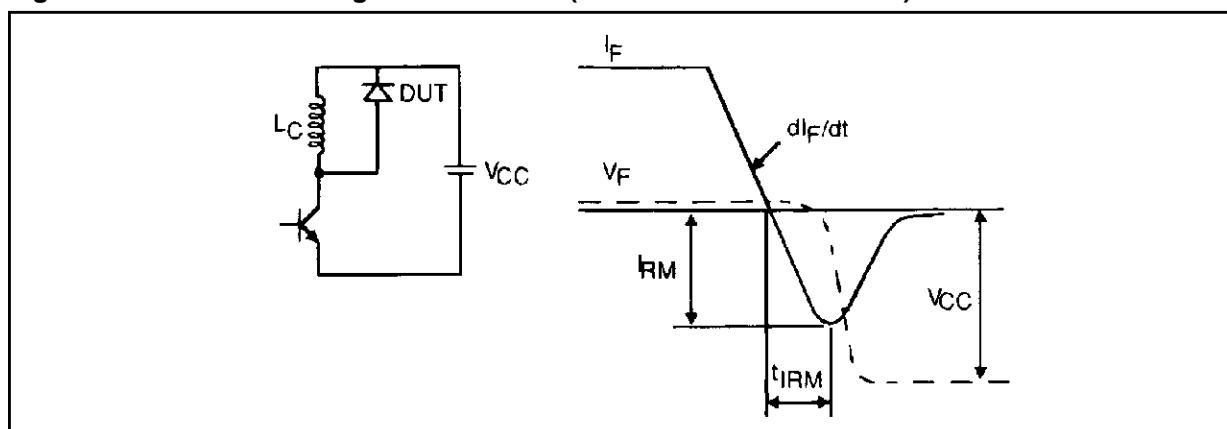
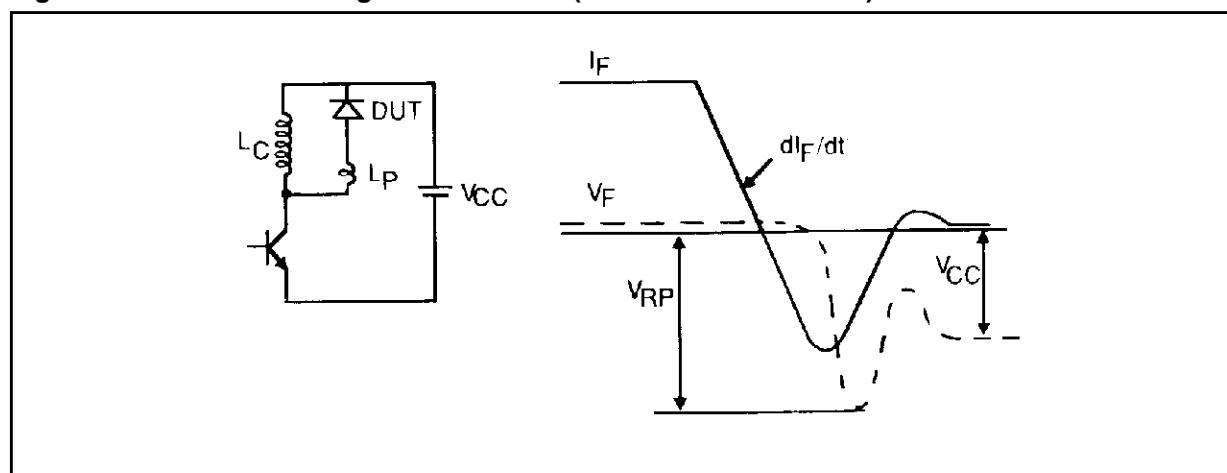
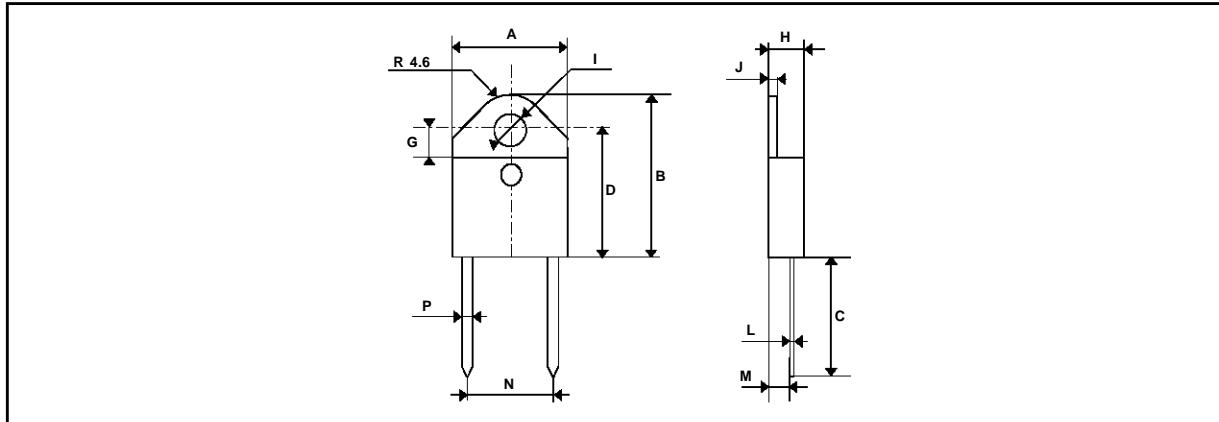


Figure 12. Turn-off switching characteristics (with series inductance)



## PACKAGE MECHANICAL DATA : Isolated DOP3I Plastic



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	15.10	15.50	0.594	0.611
B	20.70	21.10	0.814	0.831
C	14.30	15.60	0.561	0.615
D	16.10	16.50	0.632	0.650
G	3.40	-	0.133	-
H	4.40	4.60	0.173	0.182
I	4.08	4.17	0.161	0.164
J	1.45	1.55	0.057	0.062
L	0.50	0.70	0.019	0.028
M	2.70	2.90	0.106	0.115
N	10.80	11.30	0.42	0.45
P	1.20	1.40	0.047	0.056

Cooling method: by conduction (method C)

Marking: type number

Weight: 18.84g

Recommended torque value: 250cm. N

Maximum torque value: 310cm. N

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